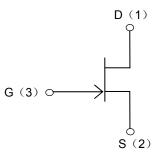


PD045G

N-Channel Junction FET

Description

- > Especially suited for use in Electret Condenser Microphone
- Ultra-small package permitting PD045G applied sets to be made smaller and slimmer
- > Excellent voltage characteristics
- Excellent transient characteristics



Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness:≤3mil

Absolute maximum rating@25℃

Parameter	Symbol	Ratings	Units
Gate to Drain Voltage	V _{GDO}	-20	V
Gate Current	I _G	10	mA
Drain Current	ID	1	mA
Allowable Power Dissipation	P _D	100	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-55 to 150	°C

Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Gate-to-Drain Breakdown Voltage	V _{(BR)GDO}	I _G =-100μΑ	-20		-	V
Cutoff Voltage	V _{GS(off)}	V _{DS} =3V,I _D =1µA	-0.2	-0.6	-1.2	V
Zero-Gate Voltage Drain Current	I _{DSS}	V_{DS} =3V, V_{GS} =0	40	-	500	uA
Forward Transfer Admittance	yfs	V_{DS} =3V, V_{GS} =0,f=1KHz	0.4	1.2		ms
Input Capacitance	CISS	V _{DS} =3V, V _{GS} =0,f=1KHz	-	3.5		pF
Reverse Transfer Capacitance	C _{RSS}	V_{DS} =3V, V_{GS} =0,f=1KHz	-	0.65		pF

N-Channel Junction FET

PD045G

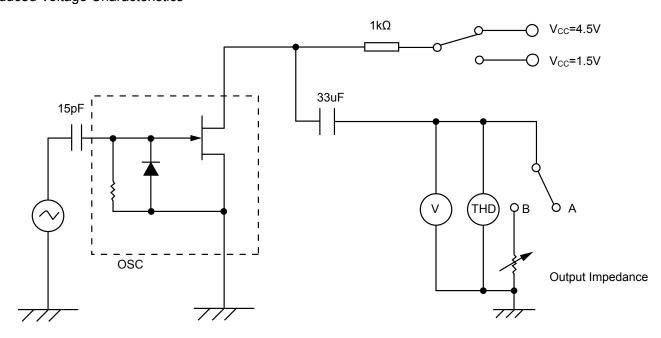
The PD045G is classified by IDSS as follows : (Units:uA)						
Rank	E31	E32	E4	E51	E53	E6
I _{DSS}	70~100	100~150	150~200	200~300	300~360	360~480

Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
T _A =25°C.V _{CC} =4.5V,R _L =1kΩ,C _{in} =15pF.						
Voltage Gain	Gv	V _{IN} =10mV,f=1KHz		-3.0	-	dB
Reduced Voltage Characteristics	∆G _{vv}	V _{IN} =10mV,f=1KHz,V _{CC} =4.5→1.5V		-1.2	-3.5	dB
Frequency Characteristics	∆G _{Vf}	f=1KHz to 110Hz			-1.0	dB
Input Resistance	Z _{IN}	f=1KHz	25			MΩ
Output Resistance	Zo	f=1KHz		1000		Ω
Total Harmonic Distortion	T _{HD}	V _{IN} =30mV,f=1KHz		1.0		%
Output Noise Voltage	V _{NO}				-110	dB

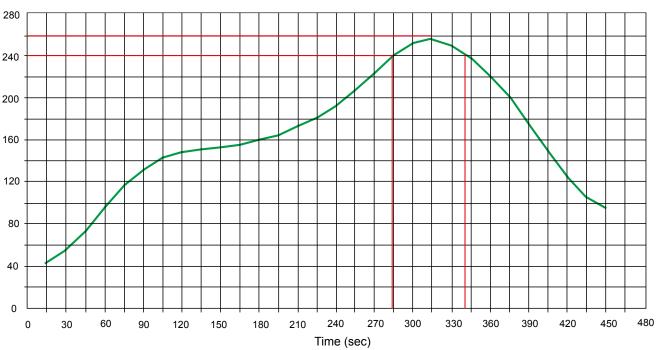
Test Circuit

Voltage gain Frequency Characteristics Distortion Reduced Voltage Characteristics



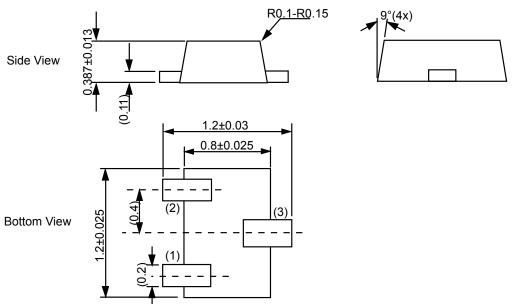
N-Channel Junction FET

Solder Reflow Recommendation



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

Product dimension (SOT-723)

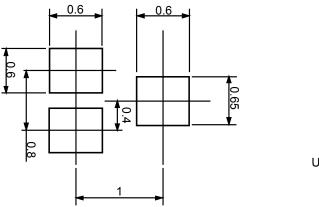


Unit: mm

PD045G

N-Channel Junction FET

PD045G



Unit: mm

Ordering information

Device	Package	Shipping
PD045G	SOT-723 (Pb-Free)	10000 / Tape & Reel

IMPORTANT NOTICE

Q and **Prisemi** are registered trademarks of **Prisemi Electronics Co., Ltd** (Prisemi), Prisemi reserves the right to make changes without further notice to any products herein. Prisemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Prisemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in Prisemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Prisemi does not convey any license under its patent rights nor the rights of others. The products listed in this document are designed to be used with ordinary electronic equipment or devices, Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Website: http://www.prisemi.com For additional information, please contact your local Sales Representative. ©Copyright 2009, Prisemi Electronics Prisemi® is a registered trademark of Prisemi Electronics. All rights are reserved.